

Single Non-inverting Buffer with 3-state Output

General Description

The ETQ74LVC1G126 is a high performance single noninverting buffer operating from a 1.65V to 5.5V supply. This device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive.

Features

- Designed for 1.65V to 5.5V VCC Operation
- Over-voltage Tolerant Inputs
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- These Devices are Pb-Free and are RoHS Compliant
- 3-State OE Input is Active-High
- MSL1
- Automotive AEC-Q100 Grade 1 Qualified
 - Ambient temperature range of -40°C to +125°C
 - ESD HBM 4KV PASS
 - ESD CDM 1KV PASS

Device Information

Part No.	Package	Size
ETQ74LVC1G126	SC70-5	2.07mm×2.30mm

Applications

- Fully compliant with standards for automotive applications
- Combine normal power signals from multiple power rails

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Pin Configuration

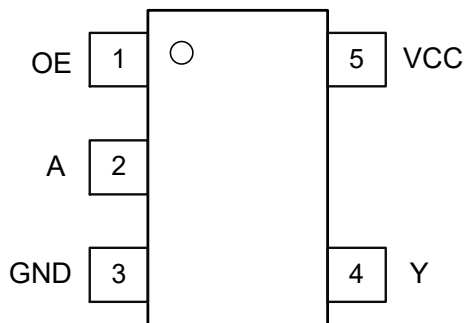


Figure1. Top View

Pin Function

Pin No.	Name	Description
1	OE	Control Pin,High Active
2	A	Input A
3	GND	Ground
4	Y	Output Y
5	VCC	Power Supply

Block Diagram

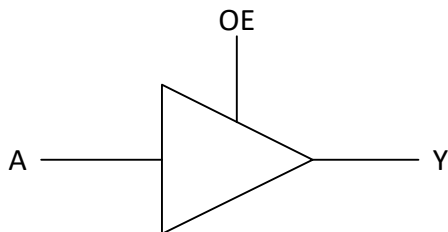


Figure2. Logic Symbol

Functional Description

Function Table

Input		Output
OE	A	Y
H	L	L
H	H	H
L	X	Z

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Absolute Maximum Ratings

Symbol	Parameter		Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to 7.0	V
V _I	DC Input Voltage		-0.5 ≤ V _I ≤ +7.0	V
V _O	DC Output Voltage Output in Higher or Low State ⁽¹⁾		-0.5 to V _{CC} + 0.5	V
I _{IK}	DC Input Diode Current	V _I < GND	-50	mA
I _{OK}	DC Output Diode Current	V _O < GND, V _O > V _{CC}	±50	mA
I _O	DC Output Sink Current		±50	mA
I _{CC}	DC Supply Current per Supply Pin		±100	mA
I _{GND}	DC Ground Current per Supply Pin		±100	mA
T _{STG}	Storage Temperature Range		-65 to 150	°C
T _L	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
T _J	Junction Temperature Under Bias		150	°C
θ _{JA}	Thermal Resistance	SC70-5	300	°C /W
P _D	Power Dissipation in Still Air at 85°C		215	mW
V _{ESD}	ESD Classification	Human Body Model ⁽²⁾	±4000	V
		Charged Device Model ⁽³⁾	±1000	
I _{LU}	Latchup Current Above V _{CC} and GND at 125°C ⁽⁴⁾		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Notes:

1. IO absolute maximum rating must be observed.
2. HBM tested per AEC-Q100-002(EIA/JESD22-A114);
3. CDM tested per AEC-Q100-011(EIA/JESD22-C101);
4. Latch up Current Maximum Rating tested per AEC-Q100-004(EIA/JESD78E).

Recommended Operating Conditions

Symbol	Parameter		Min	Max	Unit
V _{CC}	DC Supply Voltage Operating		1.65	5.5	V
	Data Retention Voltage Operating		1.5	5.5	
V _{IN}	DC Input Voltage		0	5.5	V
V _{OUT}	DC Output Voltage (High or Low State)		0	5.5	V
T _A	Operating Temperature Range		-40	125	°C
t _r , t _f	Input Rise and Fall Time	V _{CC} = 2.5 V ± 0.2 V	0	20	ns/V
		V _{CC} = 3.0 V ± 0.3 V	0	10	
		V _{CC} = 5.0 V ± 0.5 V	0	5	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied.

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Electrical Characteristics

DC Electrical Characteristics

Symbol	Parameter	Condition	V _{CC} (V)	T _A = 25 °C			-40°C ≤ T _A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
V _{IH}	High-Level Input Voltage		1.65to1.95 2.3 to 5.5	0.75V _{CC} 0.7V _{CC}			0.75V _{CC} 0.7V _{CC}		V
V _{IL}	Low-Level Input Voltage		1.65to1.95 2.3 to 5.5			0.25V _{CC} 0.3V _{CC}		0.25V _{CC} 0.3V _{CC}	V
V _{OH}	High-Level Output Voltage V _{IN} = V _{IL}	I _{OH} = -100uA	1.65to5.5	V _{CC} -0.1	V _{CC}		V _{CC} -0.1		V
		I _{OH} = -3mA	1.65	1.29	1.52		1.29		
		I _{OH} = -8mA	2.3	1.9	2.1		1.9		
		I _{OH} = -12mA	2.7	2.2	2.4		2.2		
		I _{OH} = -16mA	3.0	2.4	2.7		2.4		
		I _{OH} = -24mA	3.0	2.3	2.5		2.3		
		I _{OH} = -32mA	4.5	3.8	4.0		3.8		
V _{OL}	Low-Level Output Voltage V _{IN} = V _{IH}	I _{OH} = 100uA	1.65to5.5		0.0	0.1		0.1	V
		I _{OL} = 3mA	1.65		0.08	0.24		0.24	
		I _{OL} = 8mA	2.3		0.20	0.3		0.3	
		I _{OL} = 12mA	2.7		0.22	0.4		0.4	
		I _{OL} = 16mA	3.0		0.28	0.4		0.4	
		I _{OL} = 24mA	3.0		0.38	0.55		0.55	
		I _{OL} = 32mA	4.5		0.42	0.55		0.55	
I _{IN}	Input Leakage Current	V _{IN} = 5.5V or GND	0 to 5.5		±0.1			±1.0	uA
I _{OFF}	Power Off Leakage Current	V _{IN} = 5.5V or V _{OUT} = 5.5V	0			1		10	uA
I _{CC}	Quiescent Supply Current	V _{IN} = 5.5V or GND	5.5					10	uA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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AC Electrical Characteristics

$t_r = t_f = 2.5\text{ns}$

Symbol	Parameter	Condition	$V_{CC}(V)$	$T_A = 25^\circ\text{C}$			$-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		Unit
				Min	Typ	Max	Min	Max	
t_{PD}	Propagation Delay (Figure3 and 4)	$R_L = 1\text{M}\Omega$ $C_L = 15\text{pF}$	1.65	2.0	10.1	12.9	2.0	13.9	ns
			1.8	2.0	9.1	11.6	2.0	12.4	
			2.5	0.2	6.0	7.7	0.8	8.2	
		$R_L = 1\text{M}\Omega$ $C_L = 15\text{pF}$	3.3	0.8	5.0	6.5	0.5	7.0	
				1.2	5.6	7.1	1.5	7.6	
		$R_L = 500\Omega$ $C_L = 50\text{pF}$	5.0	0.5	4.4	5.6	0.5	6.1	
				0.8	4.8	6.1	0.8	6.6	
$t_{PZL},$ t_{PZH}	Output Enable Time (Figure5 and 6)	$R_L = 500\Omega$ $C_L = 50\text{pF}$	1.65	2.0	12.9	15.8	2.0	16.8	ns
			1.8	2.0	10.8	13.2	2.0	14.1	
			2.5	1.5	7.2	8.8	1.5	9.4	
			3.3	1.5	5.8	7.1	1.5	7.6	
			5.0	0.8	4.5	5.5	0.8	5.9	
$t_{PLZ},$ t_{PHZ}	Output Disable Time (Figure5 and 6)	$R_L = 500\Omega$ $C_L = 50\text{pF}$	1.65	2.0	11.5	14.1	2.0	15.1	ns
			1.8	2.0	9.8	12.0	2.0	12.8	
			2.5	1.5	7.7	9.5	1.5	10.1	
			3.3	1.0	7.2	8.8	1.0	9.4	
			5.0	0.5	5.4	6.8	0.5	7.3	

Capacitance Characteristics

Symbol	Parameter	Condition	Typ	Unit
C_{IN}	Input Capacitance	$V_{CC} = 5.5\text{V}, V_I = 0\text{V or } V_{CC}$	>2.5	pF
C_{PD}	Power Dissipation Capacitance ⁽⁵⁾	10MHz, $V_{CC} = 3.3\text{V}, V_I = 0\text{V or } V_{CC}$	4	pF
		10MHz, $V_{CC} = 5.5\text{V}, V_I = 0\text{V or } V_{CC}$	4	

Note5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \times V_{CC} \times f_{in} + I_{CC} \times C_{PD}$ is used to determine the no-load dynamic power consumption; $P_D = C_{PD} \times V_{CC}^2 \times f_{in} + I_{CC} \times V_{CC} \times Fig.$

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AC Test Circuit

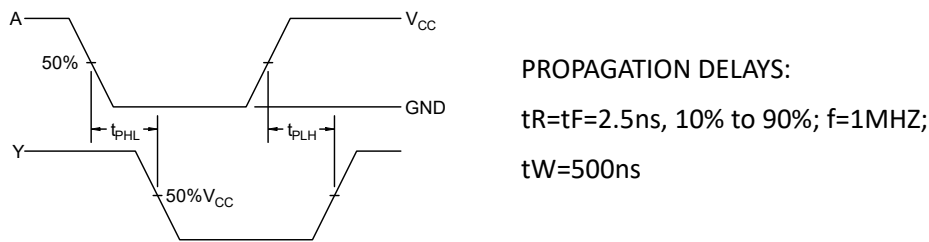


Figure 3. Switch Waveform

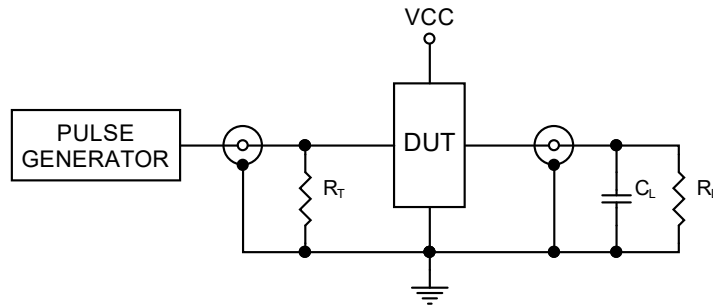


Figure 4. Test Circuit

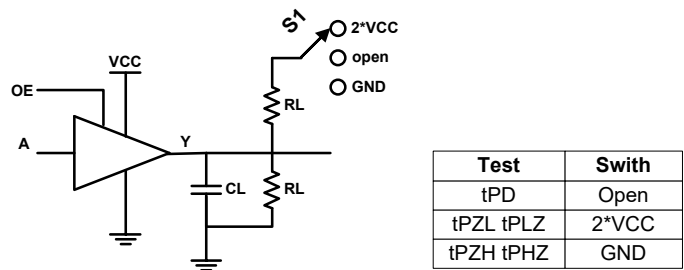


Figure 5. Output Enable/Disable Time Test Circuit

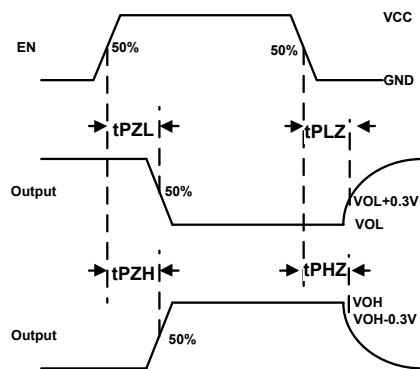
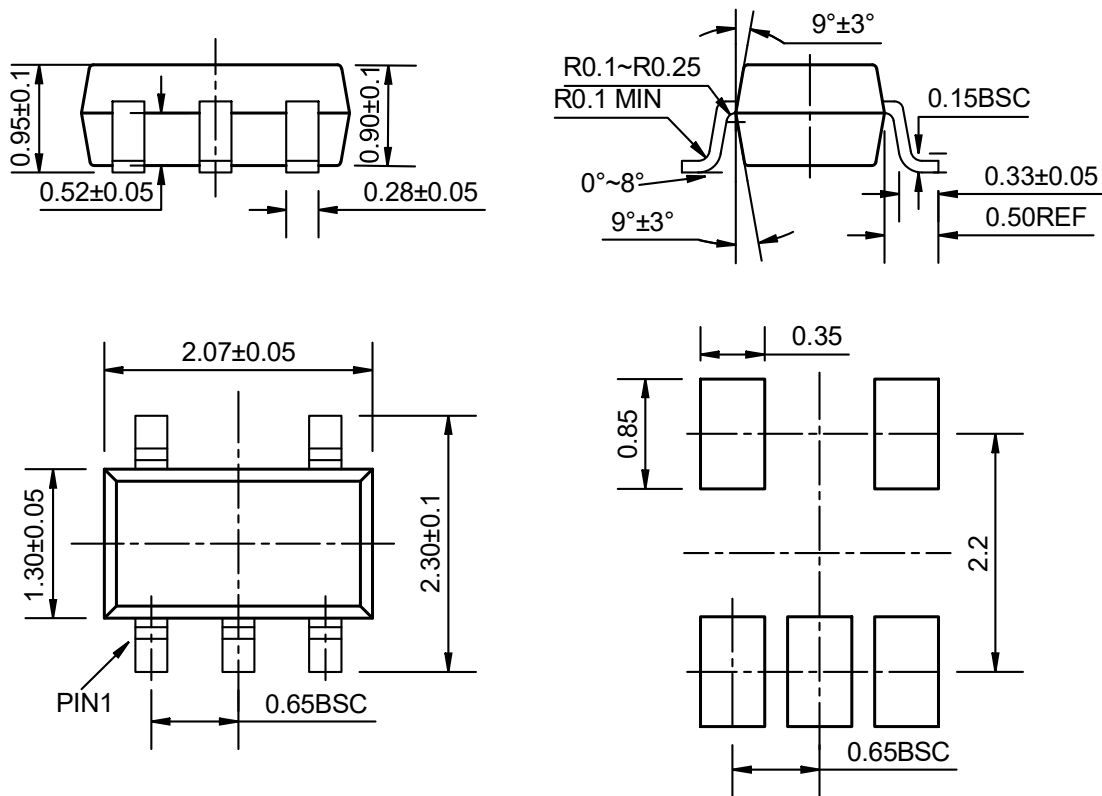


Figure 6. Output Enable/Disable Waveform

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Package Dimension

SC70-5



Recommended Land Pattern

Unit: mm

Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2017-10-23	Original Version	Ma Yong jian	Ma Yong jian	Liu Jia Ying
1.1	2023-03-06	Update Typeset ETQ version	Shibo	Shibo	Shibo